# **Switching Diode**

# BAS16L

#### Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS

| Rating   | Symbol                  | Value   | Unit |
|--|-------------------------|---|------|
| Continuous Reverse Voltage   | V <sub>R</sub>          | 100   | V    |
| Peak Forward Current   | ١ <sub>F</sub>          | 200   | mA   |
| Non-Repetitive Peak Forward Surge<br>Current 60 Hz   | I <sub>FSM(surge)</sub> | 1.8   | A    |
| Repetitive Peak Forward Current (Note 3)   | I <sub>FRM</sub>        | 1.0   | A    |
| Non-Repetitive Peak Forward Current<br>(Square Wave, $T_J = 25^{\circ}C$ prior to<br>surge)<br>t = 1 $\mu$ s<br>t = 10 $\mu$ s<br>t = 100 $\mu$ s<br>t = 1 0 ms<br>t = 10 ms<br>t = 10 ms<br>t = 1 s | IFSM                    | 36.0<br>18.0<br>6.0<br>3.0<br>1.8<br>1.3<br>1.0 | A    |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS

| Characteristic   | Symbol                            | Max         | Unit  |
|--|-----------------------------------|-------------|-------|
| Total Device Dissipation FR-5 Board<br>(Note 1)<br>T <sub>A</sub> = 25°C       | P <sub>D</sub>                    | 225         | mW    |
| Derate above 25°C  |                                   | 1.8         | mW/°C |
| Thermal Resistance,<br>Junction-to-Ambient                                     | $R_{\thetaJA}$                    | 556         | °C/W  |
| Total Device Dissipation<br>Alumina Substrate, (Note 2)<br>$T_A = 25^{\circ}C$ | P <sub>D</sub>                    | 300         | mW    |
| Derate above 25°C  |                                   | 2.4         | mW/°C |
| Thermal Resistance,<br>Junction-to-Ambient                                     | $R_{\thetaJA}$                    | 417         | °C/W  |
| Junction and Storage Temperature   | T <sub>J</sub> , T <sub>stg</sub> | -55 to +150 | °C    |

1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.

2. Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.

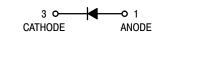
3. Square Wave, f = 40 kHz, PW = 200 ns

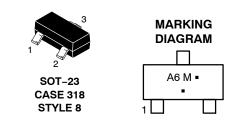
Test Duration = 60 s,  $T_J = 25^{\circ}C$  prior to surge.



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A6 = Specific Device Code M = Date Code\* • = Pb-Free Package (Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

| Device     | Package             | Shipping <sup>†</sup> |
|------------|---------------------|-----------------------|
| BAS16LT1G  | SOT-23<br>(Pb-Free) | 3000/Tape & Reel      |
| BAS16LT3G  | SOT-23<br>(Pb-Free) | 10000/Tape & Reel     |
| SBAS16LT1G | SOT-23<br>(Pb-Free) | 3000/Tape & Reel      |
| SBAS16LT3G | SOT-23<br>(Pb-Free) | 10000/Tape & Reel     |

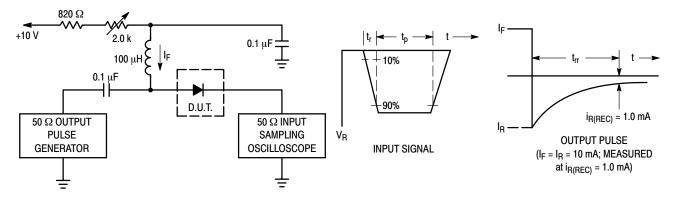
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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#### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

| Characteristic  | Symbol            | Min         | Max                        | Unit |
|---|-------------------|-------------|----------------------------|------|
| OFF CHARACTERISTICS   |                   |             |                            |      |
| Reverse Voltage Leakage Current<br>$(V_R = 100 V)$<br>$(V_R = 75 Vdc, T_J = 150^{\circ}C)$<br>$(V_R = 25 Vdc, T_J = 150^{\circ}C)$    | I <sub>R</sub>    |             | 1.0<br>50<br>30            | μAdc |
| Reverse Breakdown Voltage<br>(I <sub>BR</sub> = 100 μAdc)   | V <sub>(BR)</sub> | 100         | -                          | Vdc  |
| Forward Voltage<br>$(I_F = 1.0 \text{ mAdc})$<br>$(I_F = 10 \text{ mAdc})$<br>$(I_F = 50 \text{ mAdc})$<br>$(I_F = 150 \text{ mAdc})$ | V <sub>F</sub>    | -<br>-<br>- | 715<br>855<br>1000<br>1250 | mV   |
| Diode Capacitance<br>(V <sub>R</sub> = 0, f = 1.0 MHz)  | CD                | -           | 2.0                        | pF   |
| Forward Recovery Voltage<br>(I <sub>F</sub> = 10 mAdc, t <sub>r</sub> = 20 ns)  | V <sub>FR</sub>   | -           | 1.75                       | Vdc  |
| Reverse Recovery Time $(I_F = I_R = 10 \text{ mAdc}, R_L = 50 \Omega)$  | t <sub>rr</sub>   | -           | 6.0                        | ns   |
| Stored Charge (I <sub>F</sub> = 10 mAdc to V <sub>R</sub> = 5.0 Vdc, R <sub>L</sub> = 500 $\Omega$ )                                  | Q <sub>S</sub>    | -           | 45                         | рС   |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



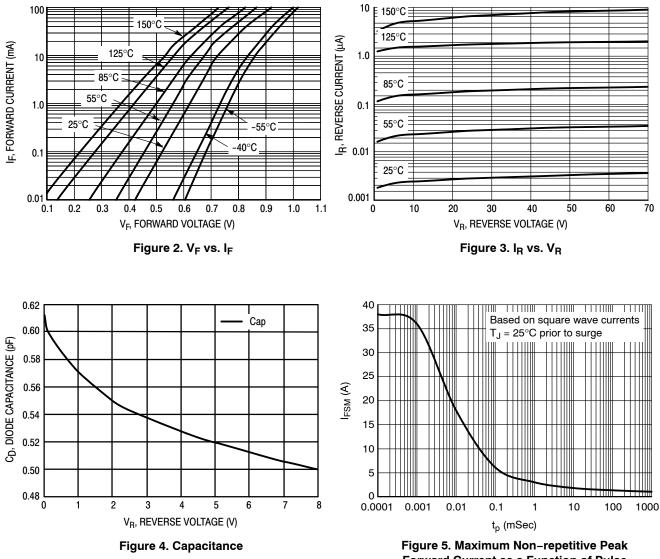
Notes: 1. A 2.0 k $\Omega$  variable resistor adjusted for a Forward Current (I<sub>F</sub>) of 10 mA. 2. Input pulse is adjusted so I<sub>R(peak)</sub> is equal to 10 mA.

3. t<sub>p</sub> » t<sub>rr</sub>

Figure 1. Recovery Time Equivalent Test Circuit

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### **TYPICAL CHARACTERISTICS**



Forward Current as a Function of Pulse Duration, Typical Values





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